DATA SHEET

GRF2003

BROADBAND GAIN BLOCK
0.1 to 10 GHz

RELEASE A DATA SHEET

FEATURES

- Flexible Bias Voltage and Current
- 50 Ω Single-Ended Input and Output Impedances
- Process: GaAs pHEMT
- Compact 1.5 x 1.5 mm DFN-6 Package
- RoHS Compliant

Reference: 5 V / 55 mA I_{DDQ} / 5.5 GHz

- Gain: 14.5 dB
- OIP3: 31 dBm
- OP1dB: 17 dBm
- Noise Figure: 3.5 dB

APPLICATIONS

- Microwave Backhaul
- C/X-Band Amplifiers
- General Purpose Amplifiers
- Instrumentation

ORDERING INFORMATION

Buy it Now

DESCRIPTION

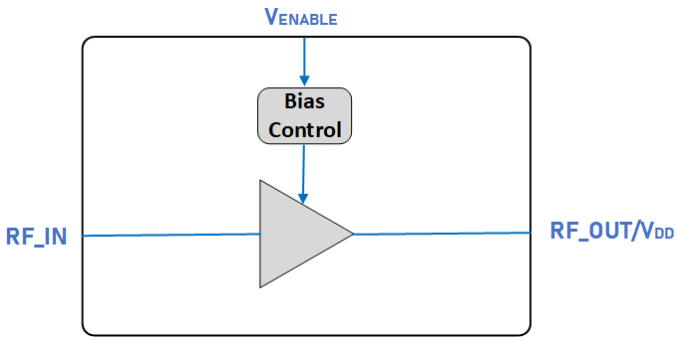
GRF2003 is a broadband, low-noise linear gain block designed for small cell, wireless infrastructure and other high-performance RF applications. A single match will offer strong RF performance over 0.5 to 10 GHz. With optimized external components, the device can be operated down to 100 MHz.

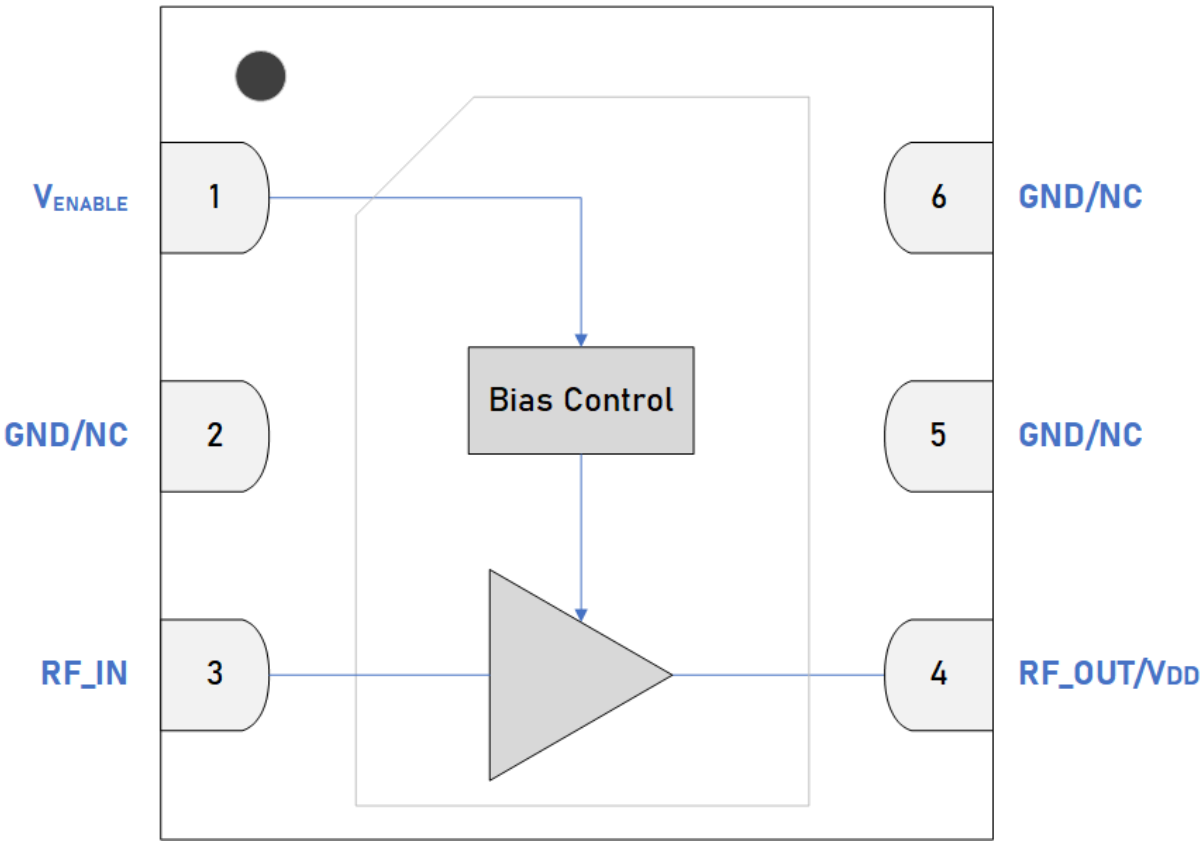
The device can be operated over a range of supply voltages from 2.7 to 5.0 V with a typical I_{DDQ} range from 40 to 80 mA for optimal efficiency and linearity.

Please consult with the GRF applications engineering team for custom tuning/evaluation board data and device S-parameters.

Additional tunes can be found on the GRF2003 "Custom Tunes" product page: GRF2003 Custom Tunes

BLOCK DIAGRAM





Pin Out (Top View)

Pin Assignments

Pin	Name	Description	Note
1	V_{ENABLE}	Enable Voltage Input	V_{ENABLE} and series resistor set I_{DDQ}. V_{ENABLE} < 0.2 volts disables the device.
2, 5, 6	GND/NC	Ground or No Connect	No internal connection to die.
3	RF_IN	LNA RF Input	Internally matched 50 Ω. An external DC blocking capacitor must be used.
4	RF_OUT/V_{DD}	LNA RF Output	Internally matched to 50 Ω. V_{DD} must be applied through an RF choke to this pin.
PKG BASE	GND	Ground	Provides DC and RF ground for LNA, as well as thermal heat sink. Recommend multiple 8 mil vias beneath the package for optimal RF and thermal performance. Refer to evaluation board top layer graphic on schematic page.

Truth Table

Pin	Voltage	Condition	Note
V_{ENABLE}	< 0.2 V	Amplifier Off	Setting V_{ENABLE} to less than 0.2 V will effectively turn the device off.
	≥ 1.8 V	Amplifier On	Set V_{ENABLE} to > 1.8 V using the appropriate M3 resistor value to achieve the targeted I_{DDQ} level.

Absolute Ratings

Parameter	Symbol	Min.	Max.	Unit
Supply Voltage	V_{DD}	0	6	V
RF Input Power: Load VSWR ≤ 2:1, V_{DD} = 5.0 V, CW tone, 100% DC, $T_{PKG\ BASE}$ = 25 °C.	$P_{IN\ MAX}$		15	dBm
Operating Temperature (Package Base)	$T_{PKG\ BASE}$	-40	105	°C
Maximum Channel Temperature (MTTF >10^6 Hours)	T_{MAX}		170	°C
Maximum Dissipated Power	$P_{DISS\ MAX}$		400	mW

Electrostatic Discharge

Charged Device Model	CDM	1500		V
Human Body Model	HBM	250		V

Storage

Storage Temperature	T_{STG}	-65	150	°C
Moisture Sensitivity Level	MSL		1	--

Caution! ESD Sensitive Device.

Exceeding Absolute Maximum Rating conditions may cause permanent damage.

Note: For additional information, please refer to Manufacturing Note MN-001 - Packaging and Manufacturing Information.

All Guerrilla RF products are provided in RoHS compliant lead (Pb)-free packaging. For additional information, please refer to the Certificate of RoHS Compliance.

Recommended Operating Conditions

Parameter	Symbol	Specification			Unit	Condition
		Min.	Typ.	Max.		
Supply Voltage	V_{DD}	1.7	5	5.25	V	
Operating Temperature (Package Base)	$T_{PKG\ BASE}$	-40		105	°C	
RF Frequency Range	F_{RF}	0.5	5.5	10	GHz	Typical application schematic with external matching components (**notes 1 & 2**).
RF_IN Port Impedance	Z_{RFIN}		50		Ω	
RF_OUT Port Impedance	Z_{RFOUT}		50		Ω	

Note 1: Operation outside of this range is supported by using different custom tunes. Examples of other optimized tunes can be found here: GRF2003 Custom Tunes

Note 2: Contact the Guerrilla RF applications team for guidance on optimizing the tuning of the device for alternative bands.

Nominal Operating Parameters - General

The following conditions apply unless noted otherwise: typical application schematic using the 0.5 to 10 GHz tuning set, 50 Ω system impedance, V_{DD} = 5 V, V_{ENABLE} = 5 V, I_{DD} = 55 mA, F_{TEST} = 5.5 GHz, $T_{PKG\ BASE}$ = 25 °C. Evaluation board losses are included within the specifications.

Parameter	Symbol	Specification			Unit	Condition
		Min.	Typ.	Max.		
Supply Current	I_{DD}		55		mA	
Enable Current	I_{ENABLE}		1.5		mA	
Switching Rise Time	t_{RISE}		1600		ns	Disabled mode to Gain mode **(note 3)**.
Switching Fall Time	t_{FALL}		1000		ns	Gain mode to disabled mode **(note 4)**.

Disabled Mode

Leakage Current	$I_{LEAKAGE}$		1		µA	V_{DD} = 5 V, V_{ENABLE} = 0 V.

Thermal Data

Thermal Resistance (Infrared Scan)	Θ_{JC}		198	°C/W		On Standard Evaluation Board. No RF applied **(note 5)**.

Note 3: Switching Time: 50% of V_{ENABLE} to 90% of P_{OUT}.

Note 4: Switching Time: 50% of V_{ENABLE} to 10% of P_{OUT}.

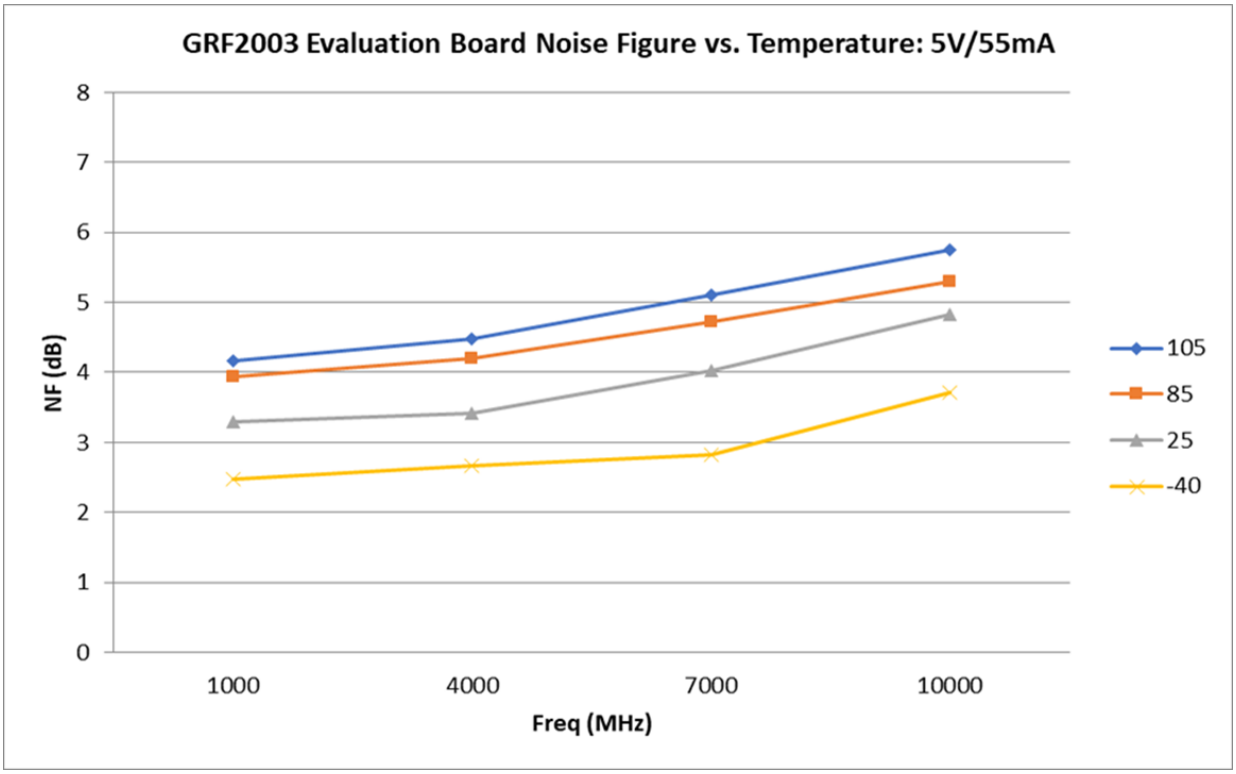
Note 5: MTTF >10^6 hours for $T_{CHANNEL}$ < 170 °C.

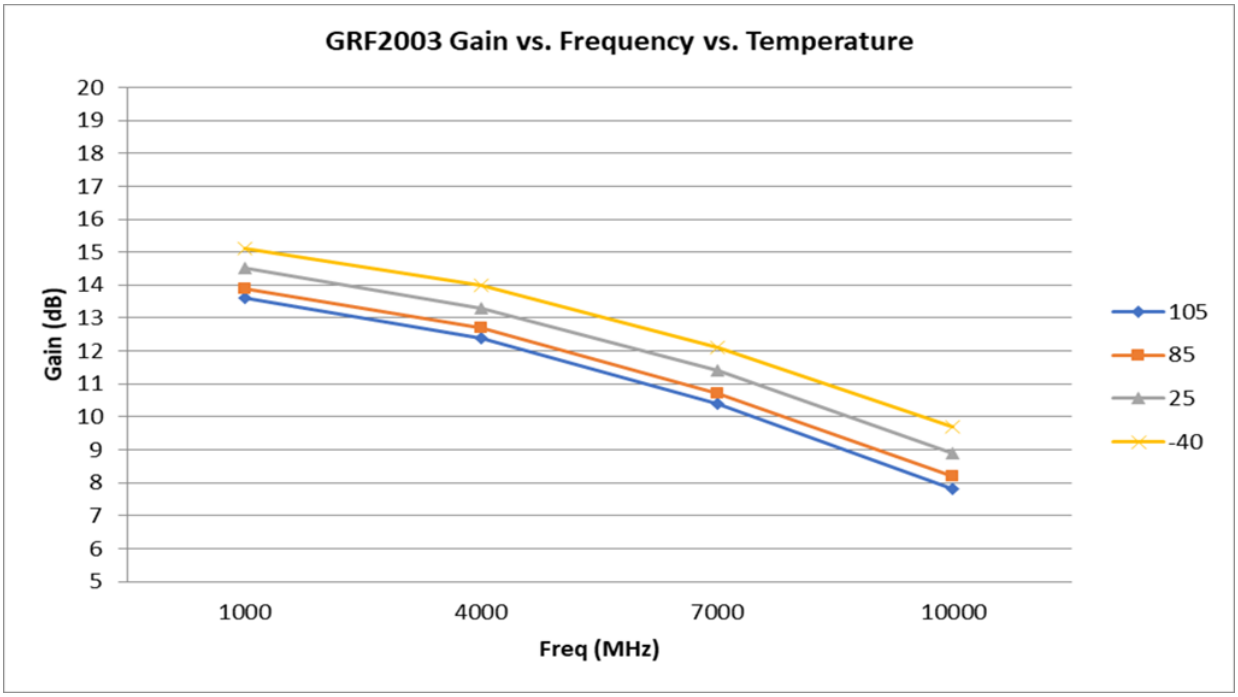
Nominal Operating Parameters - RF

The following conditions apply unless noted otherwise: typical application schematic using the 0.5 to 10 GHz tuning set, V_{DD} = 5 V, V_{ENABLE} = 5 V, I_{DD} = 55 mA, F_{TEST} = 5.5 GHz, 50 Ω system impedance, $T_{PKG\ BASE}$ = 25 °C. Evaluation board losses are included within the specifications.

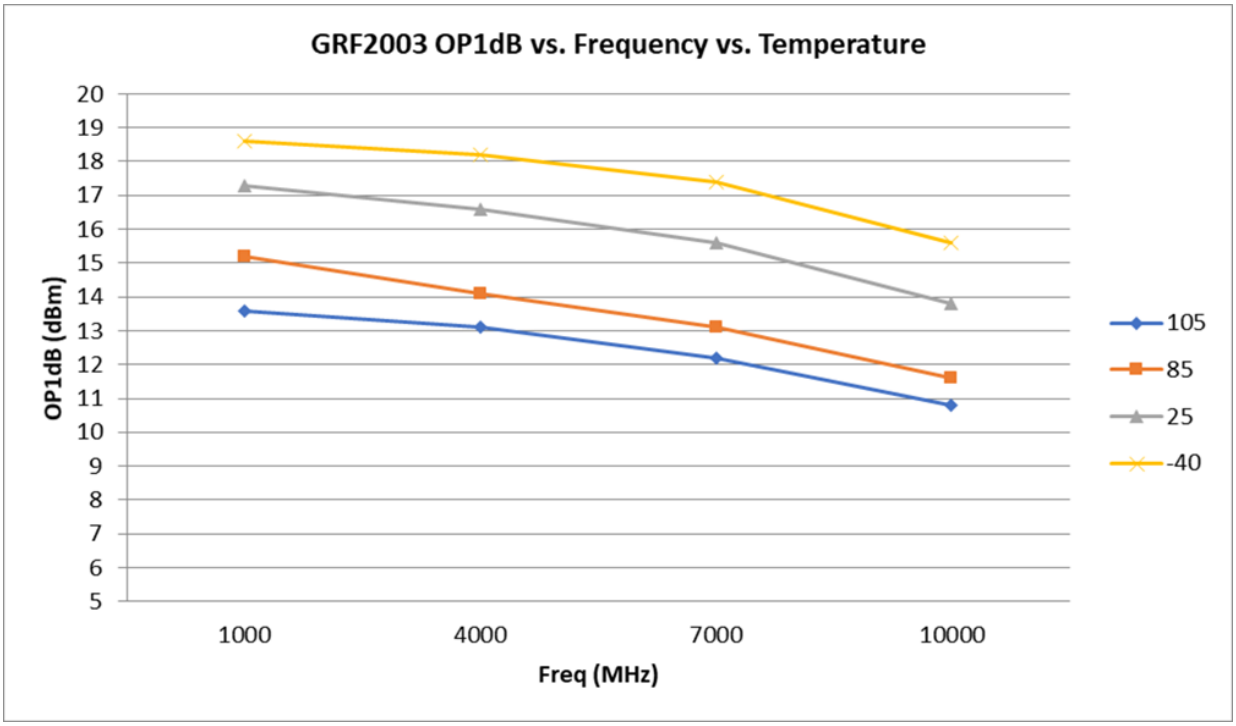
Parameter	Symbol	Specification			Unit	Condition
		Min.	Typ.	Max.		
Gain	S21	11	14.5		dB	F_{TEST} = 5.5 GHz, V_{DD} = 5 V, $T_{PKG\ BASE}$ = 25 °C.
Reverse Isolation	S12		< -21		dB	F_{RF} = 0.1 to 10 GHz
Noise Figure	NF		3.5		dB	On standard evaluation board.
Output 3rd Order Intercept Point	OIP3		31		dBm	0 dBm P_{OUT} per tone at 2 MHz spacing (5499 and 5501 MHz).
Output 1 dB Compression Power	OP1dB	12.5	17		dBm	Sine wave input, V_{DD} = 5 V, $T_{PKG\ BASE}$ = 25 °C

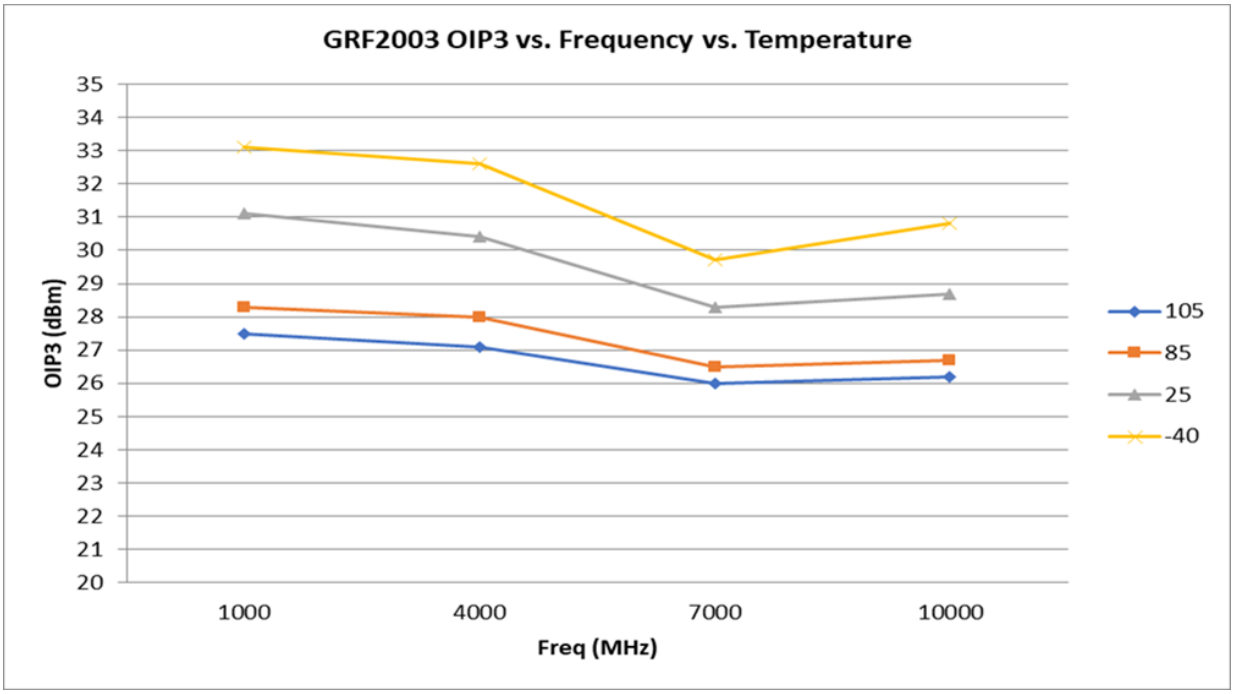
GRF2003 Typical Operating Curves: 1 to 10 GHz Tune



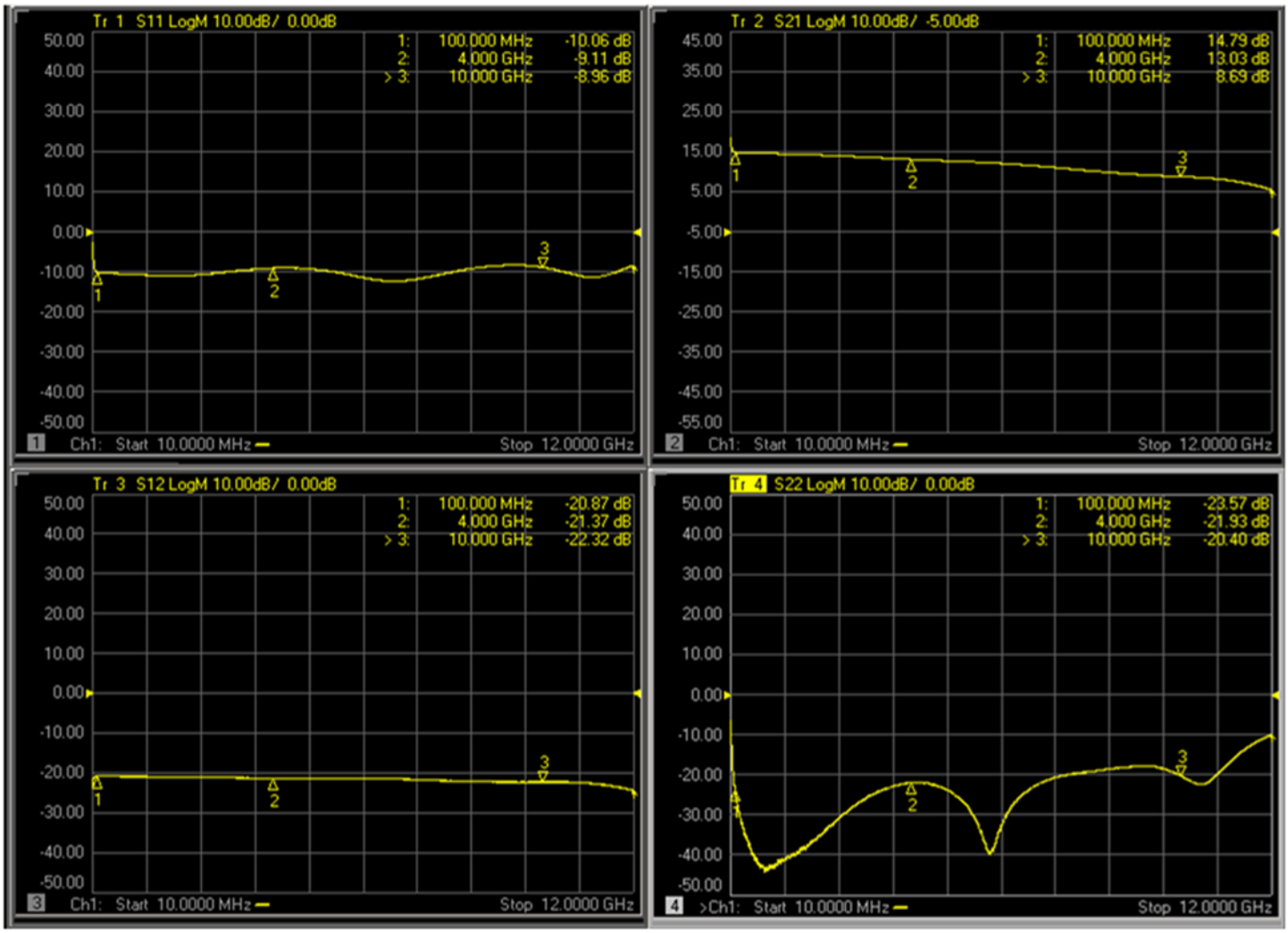


GRF2003 Typical Operating Curves: 1 to 10 GHz Tune

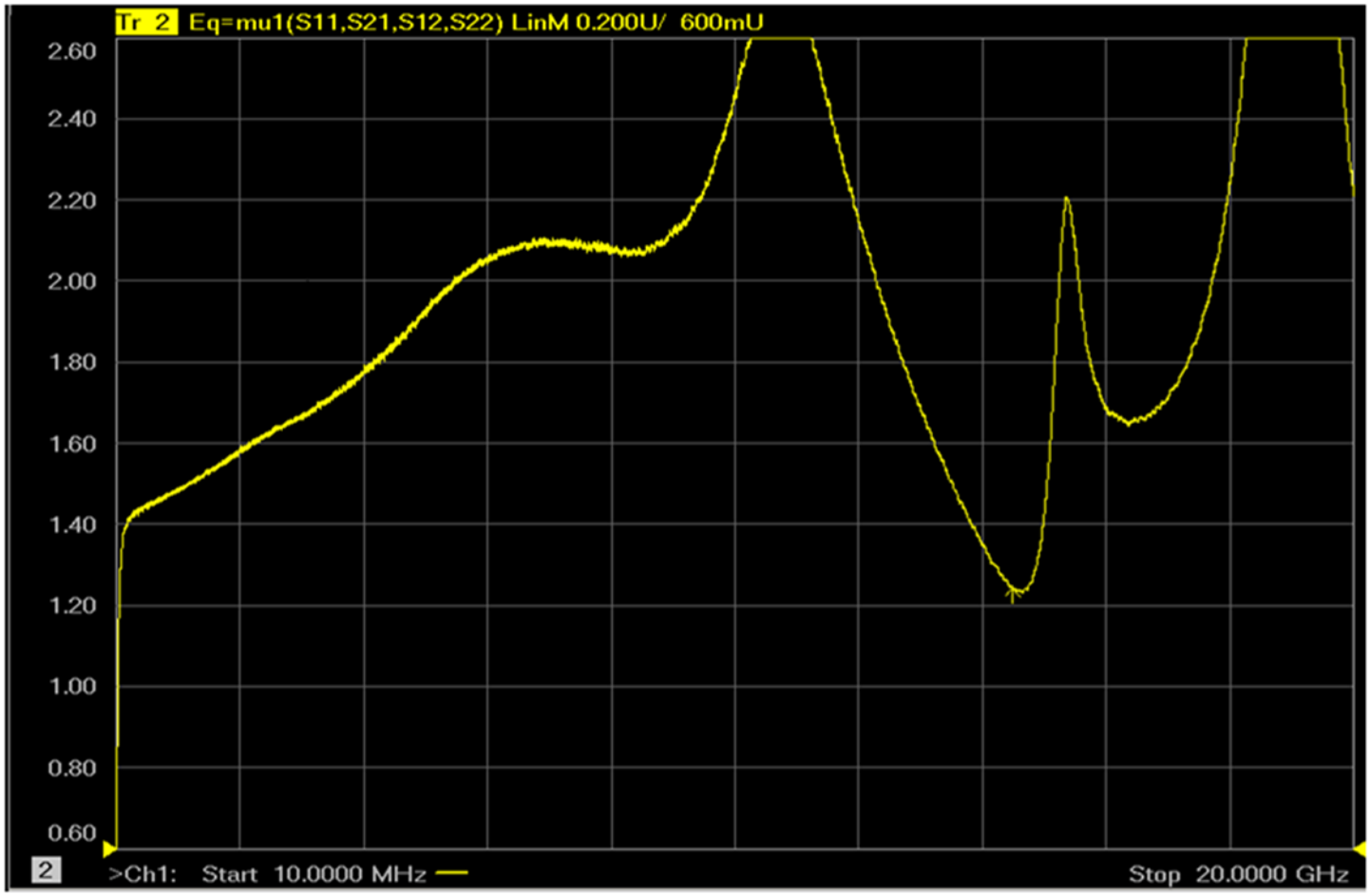




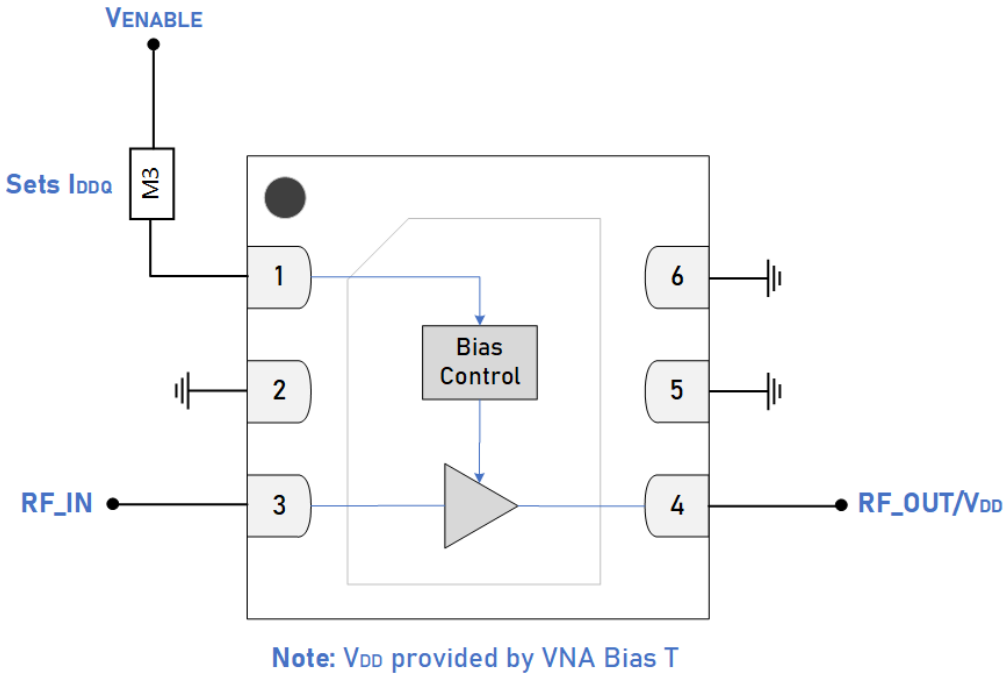
GRF2003 Typical Operating Curves: S-Parameters (0.1 to 10 GHz Tune)



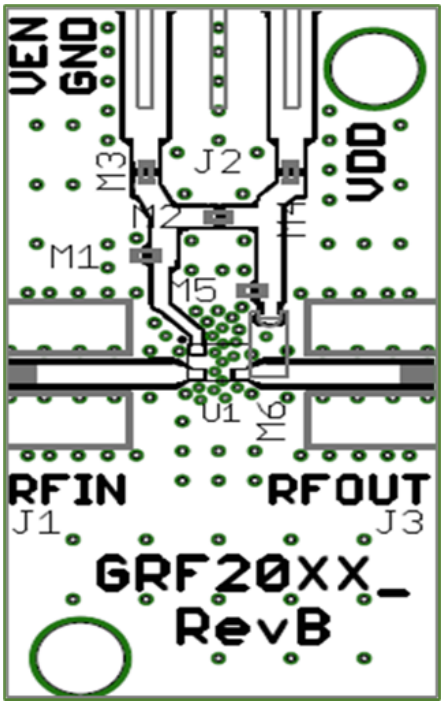
GRF2003 Typical Operating Curves: Stability Mu Factor (10 MHz to 20 GHz)



Note: Mu factor ≥1.0 implies unconditional stability.



GRF2003 Standard Evaluation Board Schematic

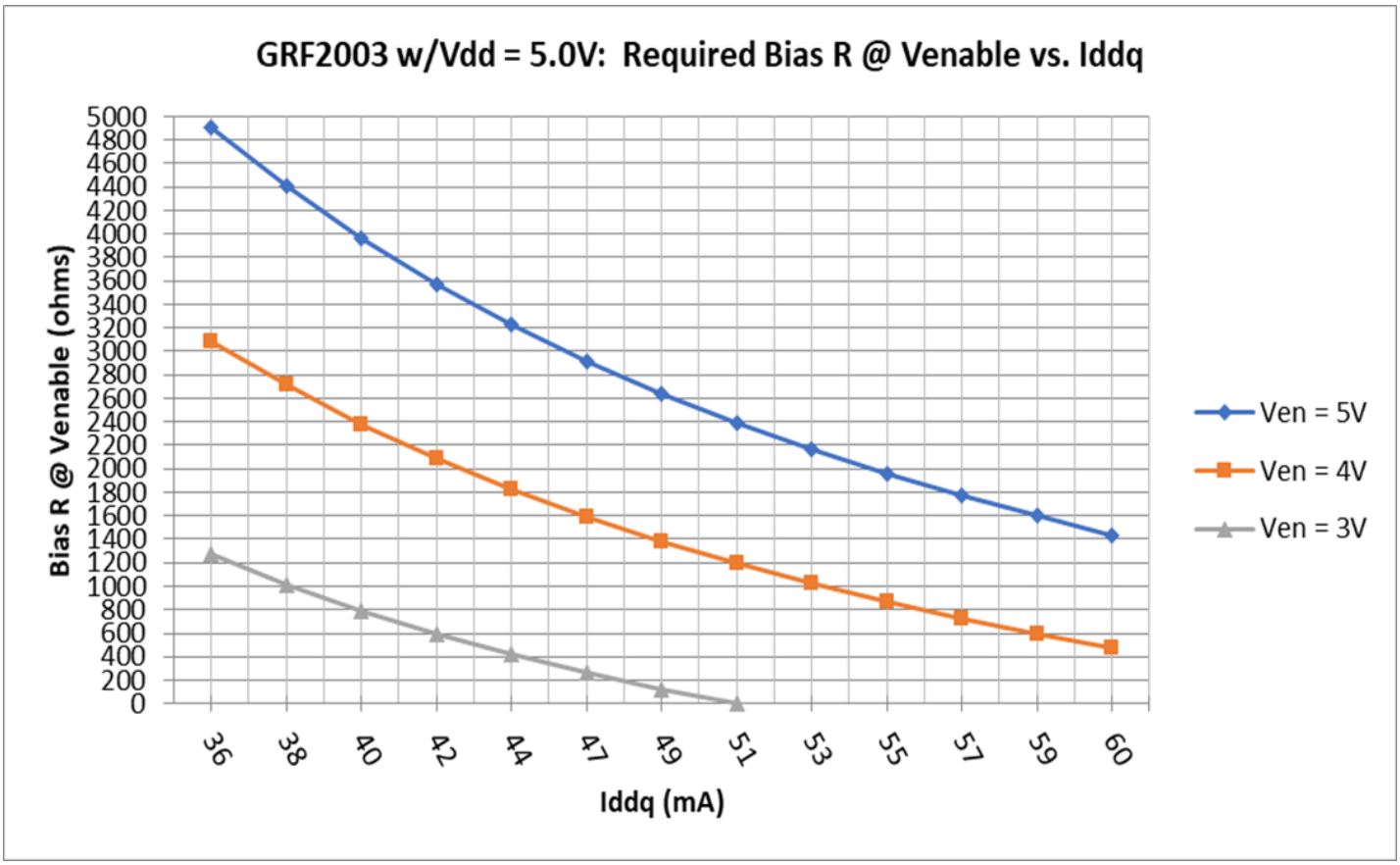


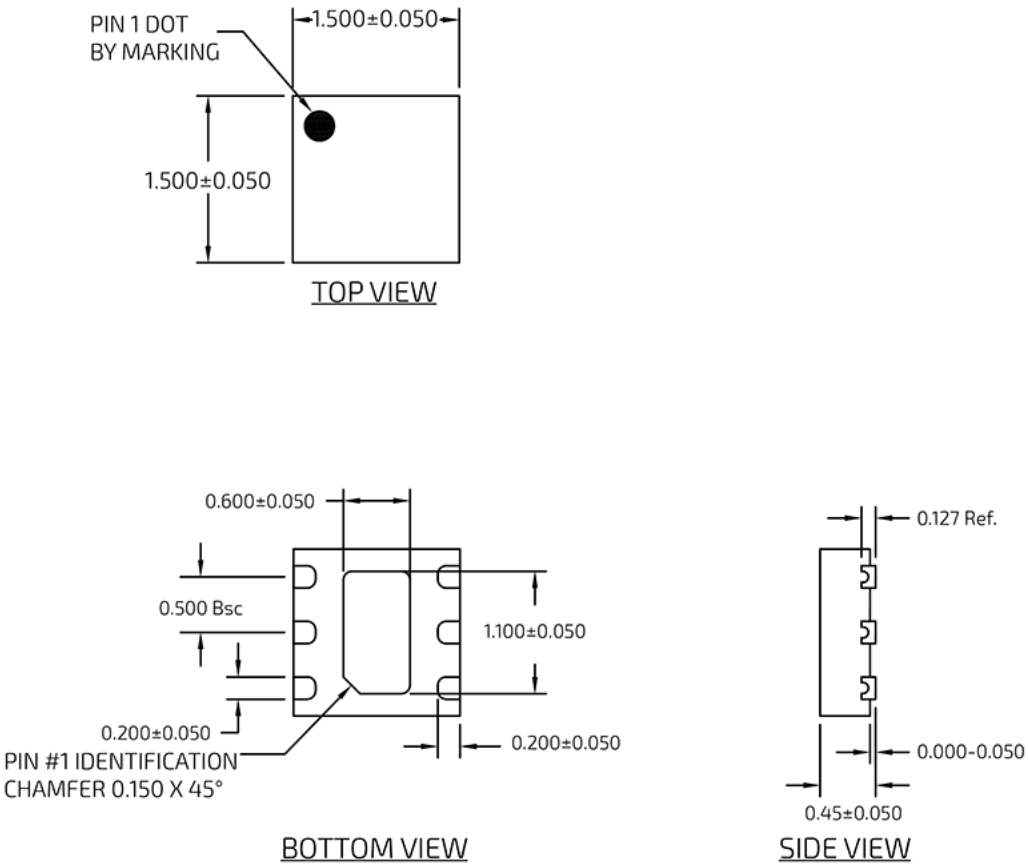
GRF2003 Evaluation Board Assembly Diagram

GRF2003 Evaluation Board Assembly Diagram Reference

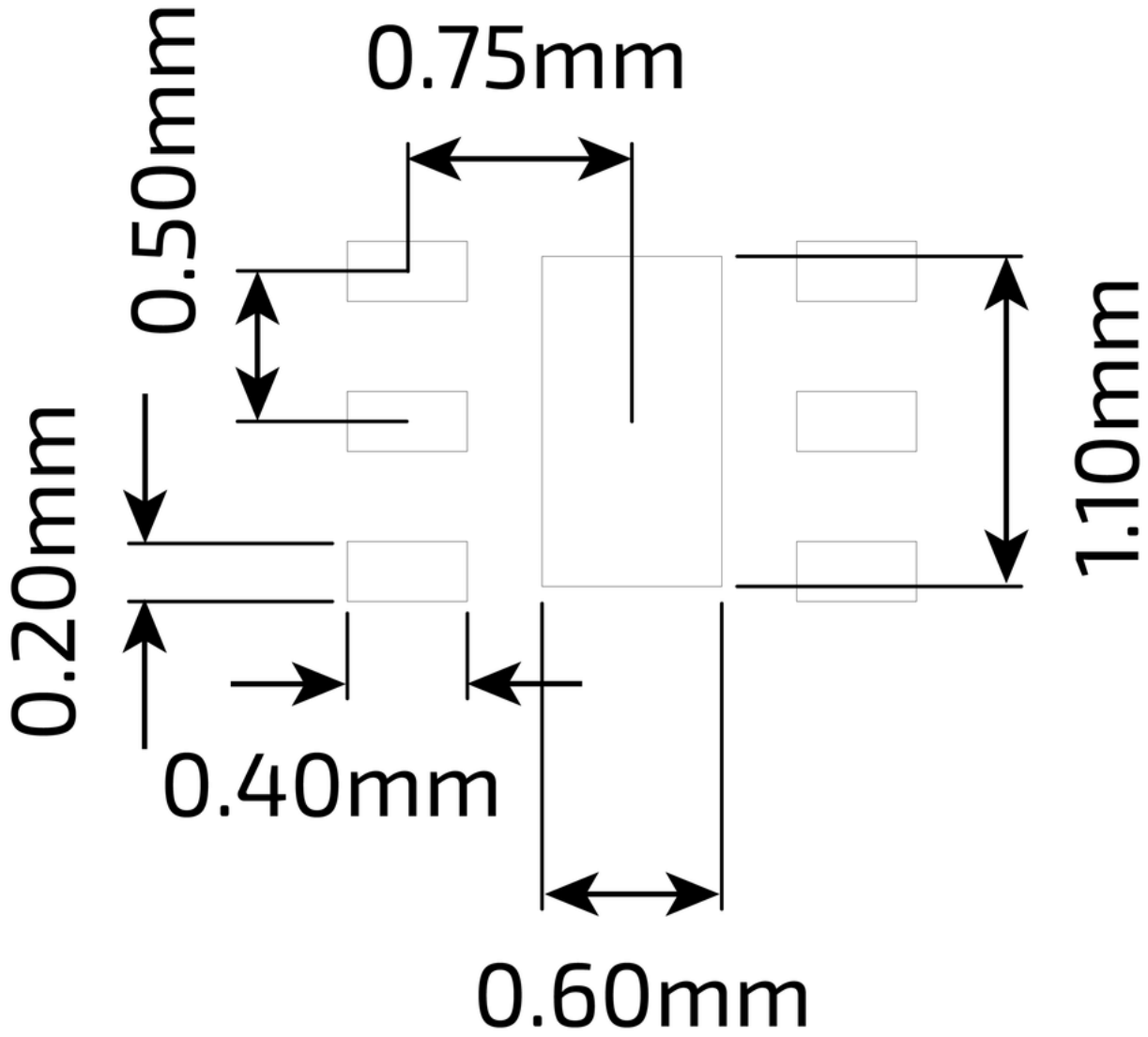
Component	Type	Manufacturer	Family	Value	Package Size	Substitution
M3 (sets I_{DDQ})	Resistor	Various	5%	see curves	0402	ok
Evaluation Board	GRF20XX_RevB					

GRF2003 Bias Resistor Selection Curves





DFN 6 1.5x1.5mm Package Dimensions



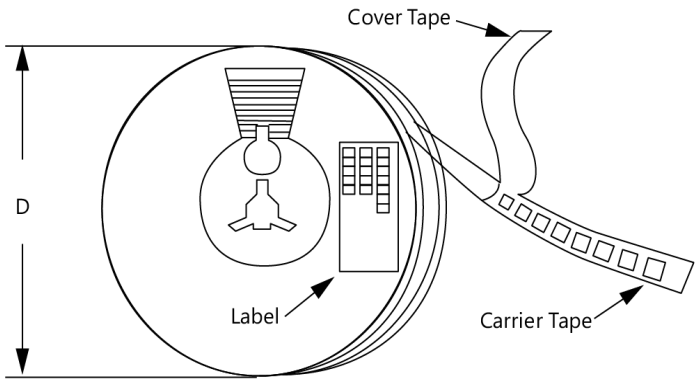
DFN 6 1.5x1.5mm Suggested PCB Footprint (Top View)

Package Marking Diagram

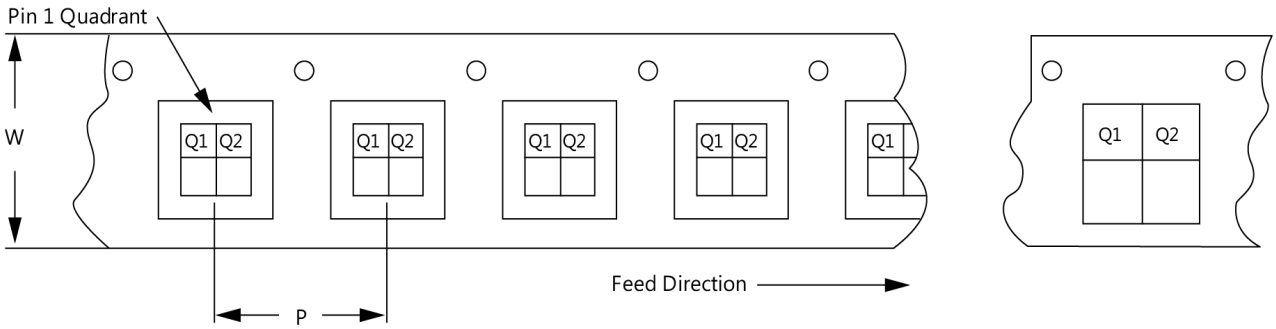
Line 1: "Y" = YEAR (single digit). "WW" = WORK WEEK the Device was assembled.
Line 2: "XXXX" = Device Part Number.

Tape and Reel Information

Guerrilla RF's tape and reel specification complies with Electronics Industries Association (EIA) standards for "Embossed Carrier Tape of Surface Mount Components for Automatic Handling" (reference EIA-481). Devices are loaded with pins down into the carrier pocket with protective cover tape and reeled onto a plastic reel. Each reel is packaged in a cardboard box. There are product labels on the reel, the protective ESD bag, and the outside surface of the box. For the latest reel specifications and package information (including units/reel), please visit Package Manufacturing Information | Guerrilla RF (guerrilla-rf.com).



Tape and Reel Packaging with Reel Diameter Noted (D)



Carrier Tape Width (W), Pitch (P), Feed Direction and Pin 1 Quadrant Information

Revision History

Revision Date	Description of Change
January 13, 2017	Preliminary Data Sheet.
May 26, 2021	Release A Data Sheet. Upgraded Data Sheet to new format.
October 4, 2023	Upgraded Data Sheet to newest format only.

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Data Sheet Classifications

Data Sheet Status	Notes
Advance	S-parameter and NF data based on EM simulations for the fully packaged device using foundry-supplied transistor S-parameters. Linearity estimates based on device size, bias condition and experience with related devices.
Preliminary	All data based on evaluation board measurements taken within the Guerrilla RF Applications Lab. Any MIN/MAX limits represented within the data sheet are based solely on *estimated* part-to-part variations and process spreads. All parametric values are subject to change pending the collection of additional data.
Release Ø	All data based on measurements taken with *production-released* material. TYP values are based on a combination of ATE and bench-level measurements, with MIN/MAX limits defined using *modelled estimates* that account for part-to-part variations and expected process spreads. Although unlikely, future refinements to the TYP/MIN/MAX values may be in order as multiple lots are processed through the factory.
Release A-Z	All data based on measurements taken with production-released material *derived from multiple lots which have been fabricated over an extended period of time*. MIN/MAX limits may be refined over previous releases as more statistically significant data is collected to account for process spreads.

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